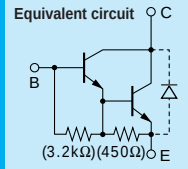


Darlington

2SD2557



Silicon NPN Triple Diffused Planar Transistor

Application : Series Regulator and General Purpose

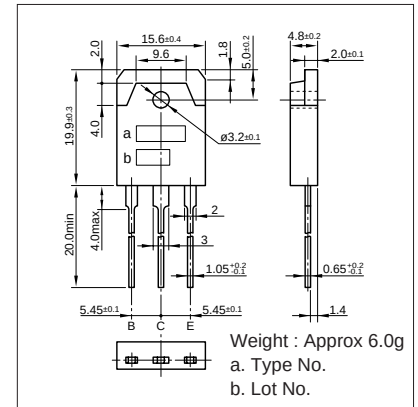
Absolute maximum ratings (Ta=25°C)

Symbol	2SD2557	Unit
V _{CB0}	200	V
V _{CEO}	200	V
V _{EB0}	6	V
I _C	5	A
I _B	2	A
P _C	70(T _C =25°C)	W
T _j	150	°C
T _{stg}	-55 to +150	°C

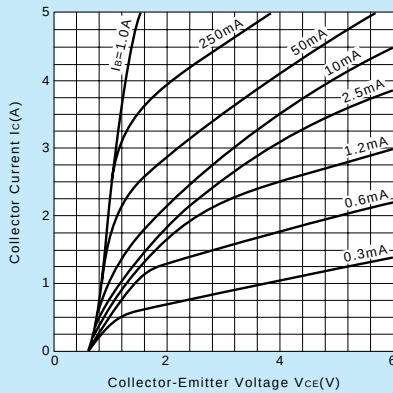
Electrical Characteristics (Ta=25°C)

Symbol	Conditions	2SD2557	Unit
I _{CBO}	V _{CB} =200V	100max	μA
I _{EBO}	V _{EB} =6V	5max	mA
V _{(BR)CEO}	I _C =10mA	200min	V
h _{FE}	V _{CE} =5V, I _C =1A	1500 to 6500	
V _{CE(sat)}	I _C =1A, I _B =5mA	1.5max	V
f _r	V _{CE} =10V, I _E =-0.5A	15typ	MHz
COB	V _{CB} =10V, f=1MHz	110typ	pF

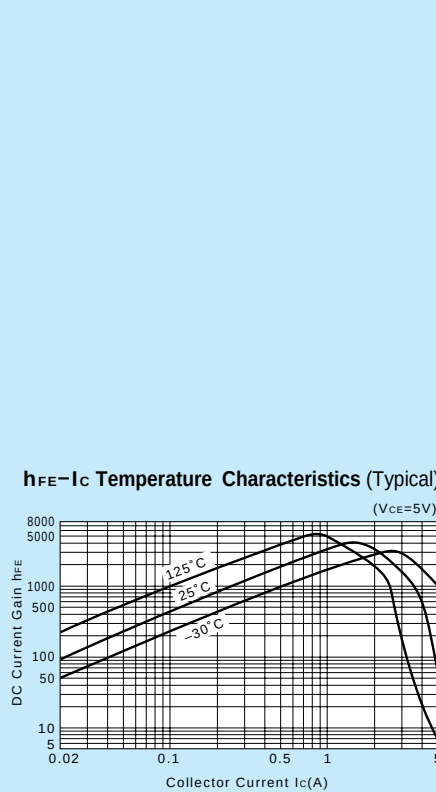
External Dimensions MT-100(TO3P)



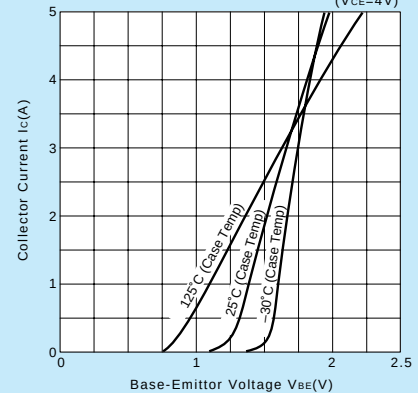
I_C-V_{CE} Characteristics (Typical)



V_{CE(sat)}-I_B Characteristics (Typical)

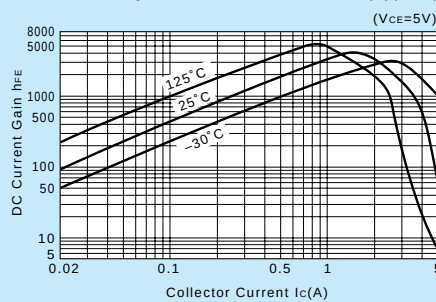


I_C-V_{BE} Temperature Characteristics (Typical)

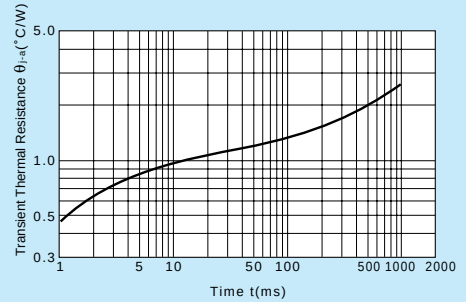


h_{FE}-I_C Characteristics (Typical)

h_{FE}-I_C Temperature Characteristics (Typical)

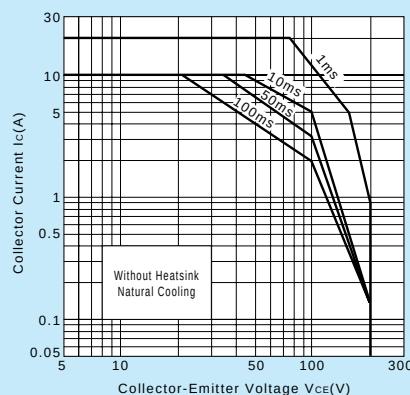


θ_{j-a}-t Characteristics



f_T-I_E Characteristics (Typical)

Safe Operating Area (Single Pulse)



P_C-T_a Derating

